

TO-92 Plastic-Encapsulate Transistors

2N5087 TRANSISTOR (PNP)

FEATURES

- General Purpose Amplifier Transistor

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

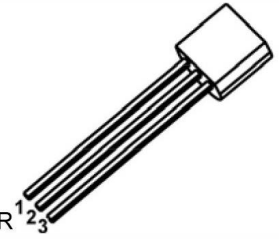
Symbol	Parameter	Value	Unit
V_{CB0}	Collector-Base Voltage	-50	V
V_{CEO}	Collector-Emitter Voltage	-50	V
V_{EBO}	Emitter-Base Voltage	-3	V
I_C	Collector Current	-50	mA
P_C	Collector Power Dissipation	625	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	200	$^\circ\text{C}/\text{W}$
T_j	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^\circ\text{C}$

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1. EMITTER

2. BASE

3. COLLECTOR

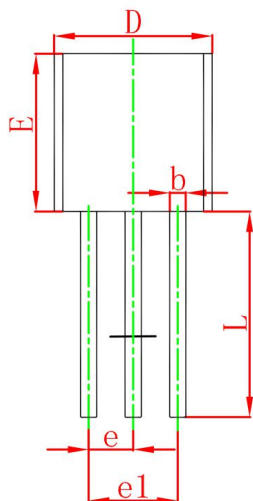
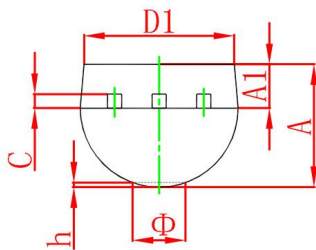


ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-0.1\text{mA}, I_E=0$	-50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-1\text{mA}, I_B=0$	-50			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-0.01\text{mA}, I_C=0$	-3			V
Collector cut-off current	I_{CBO}	$V_{CB}=-35\text{V}, I_E=0$			-50	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=-3\text{V}, I_C=0$			-50	nA
DC current gain	$h_{FE(1)}$ *	$V_{CE}=-5\text{V}, I_C=-0.1\text{mA}$	250		800	
	$h_{FE(2)}$ *	$V_{CE}=-5\text{V}, I_C=-1\text{mA}$	250			
	$h_{FE(3)}$ *	$V_{CE}=-5\text{V}, I_C=-10\text{mA}$	250			
Collector-emitter saturation voltage	$V_{CE(sat)}$ *	$I_C=-10\text{mA}, I_B=-1\text{mA}$			-0.3	V
Base-emitter voltage	V_{BE} *	$V_{CE}=-5\text{V}, I_C=-10\text{mA}$			-0.85	V
Collector output capacitance	C_{ob}	$V_{CB}=-5\text{V}, I_E=0, f=1\text{MHz}$			4	pF
Transition frequency	f_T	$V_{CE}=-5\text{V}, I_C=-0.5\text{mA}, f=100\text{MHz}$	40			MHz

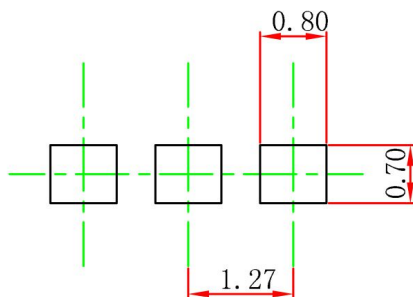
*Pulse test: pulse width $\leq 380\mu\text{s}$, duty cycle $\leq 2.0\%$.

TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

TO-92 Suggested Pad Layout



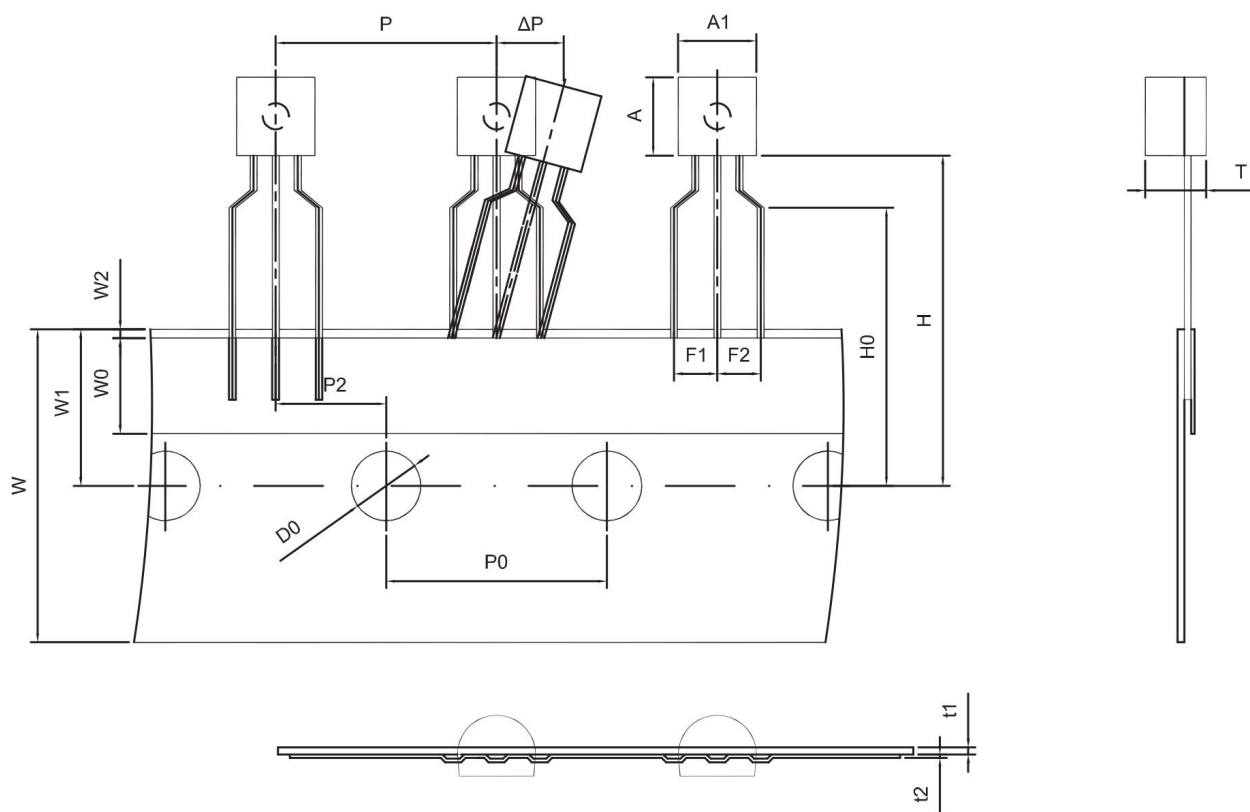
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

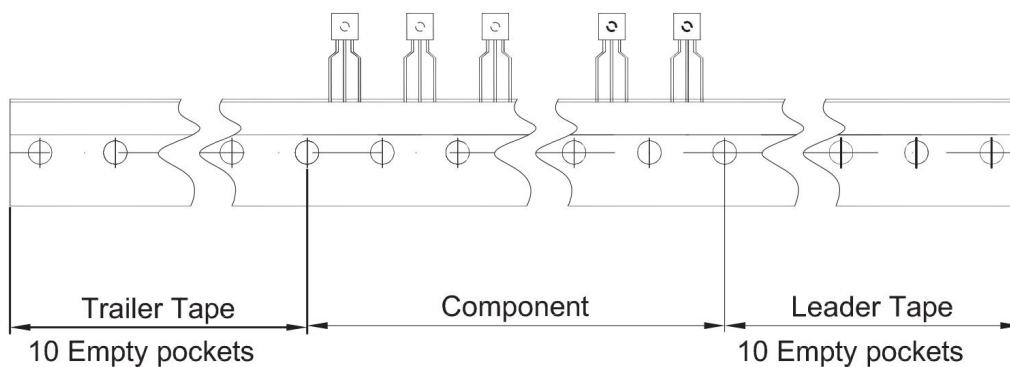
NOTICE

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TO-92 PACKAGE TAPEING DIMENSION



Dimensions are in millimeter								
A1	A	T	P	P0	P2	F1	F2	W
4.5±0.2	4.5±0.2	3.5±0.2	12.7±0.3	12.7±0.2	6.35±0.3	2.5±0.3	2.5±0.3	18.0+1.0/-0.5
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0±0.5	9.0±0.5	1.0 MAX.	19.0±1.0	16.0±0.5	4.0±0.2	0.4±0.05	0.2±0.05	0 ± 1.0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250